A 40-GHz Frequency Divider in 0.18- μ m CMOS Technology

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Abstract

A frequency divider employs resonance techniques by means of on-chip spiral inductors to operate at high speeds. Configured as two cascaded $\div 2$ stages, the circuit achieves a frequency range of 2.3 GHz at 40 GHz while consuming 31 mW from a 2.5-V supply.